

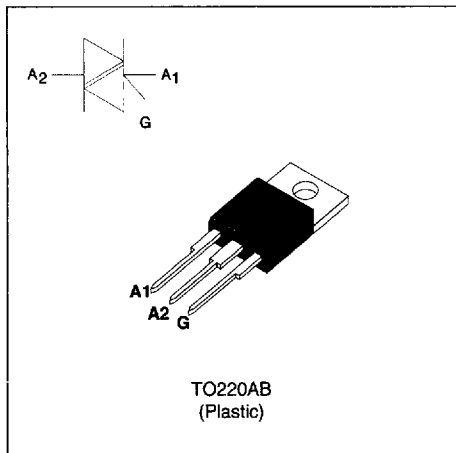
SENSITIVE GATE TRIACS

FEATURES

- VERY LOW $I_{GT} = 10\text{mA max}$
- LOW $I_H = 15\text{mA max}$
- BTA Family :
 INSULATING VOLTAGE = 2500V(RMS)
 (UL RECOGNIZED : E81734)

DESCRIPTION

The BTA/BTB06 T/D/S/A triac family are high performance glass passivated PNP devices. These parts are suitable for general purpose applications where gate high sensitivity is required. Application on 4Q such as phase control and static switching.



ABSOLUTE RATINGS (limiting values)

Symbol	Parameter			Value	Unit
IT(RMS)	RMS on-state current (360° conduction angle)	BTA	Tc = 85°C	6	A
		BTB	Tc = 90°C		
ITSM	Non repetitive surge peak on-state current (TJ initial = 25°C)	tp = 8.3 ms		63	A
		tp = 10 ms		60	
I2t	I2t value	tp = 10 ms		18	A2s
di/dt	Critical rate of rise of on-state current Gate supply : IG = 50mA diG/dt = 0.1A/μs	Repetitive F = 50 Hz		10	A/μs
		Non Repetitive		50	
Tstg Tj	Storage and operating junction temperature range			- 40 to + 150 - 40 to + 110	°C °C
TI	Maximum lead temperature for soldering during 10 s at 4.5 mm from case			260	°C

Symbol	Parameter	BTA / BTB06-			Unit
		400 T/D/S/A	600 T/D/S/A	700 T/D/S/A	
V_{DRM} V_{RRM}	Repetitive peak off-state voltage $T_j = 110^\circ\text{C}$	400	600	700	V

THERMAL RESISTANCES

Symbol	Parameter		Value	Unit
R _{th} (j-a)	Junction to ambient		60	°C/W
R _{th} (j-c) DC	Junction to case for DC	BTA	4.4	°C/W
		BTB	3.2	
R _{th} (j-c) AC	Junction to case for 360° conduction angle (F = 50 Hz)	BTA	3.3	°C/W
		BTB	2.4	

GATE CHARACTERISTICS (maximum values)

P_G (AV) = 1W P_{GM} = 10W (t_p = 20 μs) I_{GM} = 4A (t_p = 20 μs) V_{GM} = 16V (t_p = 20 μs).

ELECTRICAL CHARACTERISTICS

Symbol	Test Conditions		Quadrant		Suffix				Unit
					T	D	S	A	
I _{GT}	V _D =12V (DC) R _L =33Ω	T _J =25°C	I-II-III	MAX	5	5	10	10	mA
			IV	MAX	5	10	10	25	
V _{GT}	V _D =12V (DC) R _L =33Ω	T _J =25°C	I-II-III-IV	MAX	1.5				V
V _{GD}	V _D =V _{DRM} R _L =3.3kΩ	T _J =110°C	I-II-III-IV	MIN	0.2				V
t _{gt}	V _D =V _{DRM} I _G = 40mA dI _G /dt = 0.5A/μs	T _J =25°C	I-II-III-IV	TYP	2				μs
I _L	I _G = 1.2 I _{GT}	T _J =25°C	I-III-IV	TYP	10	10	20	20	mA
			II		20	20	40	40	
I _H *	I _T = 100mA gate open	T _J =25°C		MAX	15	15	25	25	mA
V _{TM} *	I _{TM} = 8.5A t _p = 380μs	T _J =25°C		MAX	1.65				V
I _{DRM} I _{RRM}	V _{DRM} Rated V _{RRM} Rated	T _J =25°C		MAX	0.01				mA
		T _J =110°C	MAX	0.75					
dV/dt *	Linear slope up to V _D =67%V _{DRM} gate open	T _J =110°C		TYP	10	10	-	-	V/μs
				MIN	-	-	10	10	
(dV/dt) _c *	(dI/dt) _c = 2.7A/ms	T _J =110°C		TYP	1	1	5	5	V/μs

* For either polarity of electrode A₂ voltage with reference to electrode A₁.

ORDERING INFORMATION

Package	IT(RMS)	VDRM / VRRM	Sensitivity Specification			
	A	V	T	D	S	A
BTA (Insulated)	6	400	X	X	X	X
		600	X	X	X	X
		700	X	X	X	X
BTB (Uninsulated)		400	X	X	X	X
		600	X	X	X	X
		700	X	X	X	X

Fig.1 : Maximum RMS power dissipation versus RMS on-state current ($F=50\text{Hz}$).
(Curves are cut off by $(di/dt)_c$ limitation)

Fig.2 : Correlation between maximum RMS power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTA).

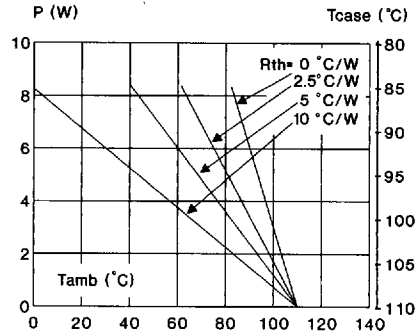
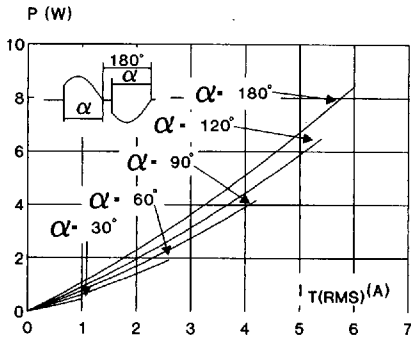


Fig.3 : Correlation between maximum RMS power dissipation and maximum allowable temperatures (T_{amb} and T_{case}) for different thermal resistances heatsink + contact (BTB).

Fig.4 : RMS on-state current versus case temperature.

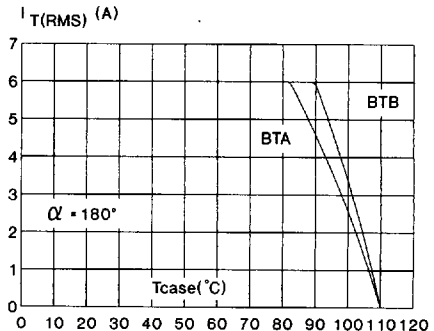
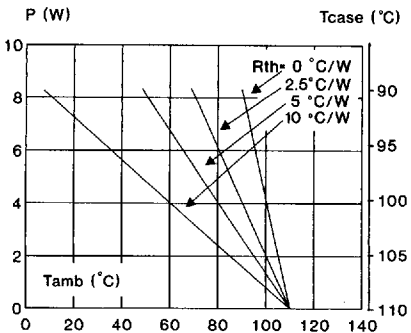


Fig.5 : Relative variation of thermal impedance versus pulse duration.

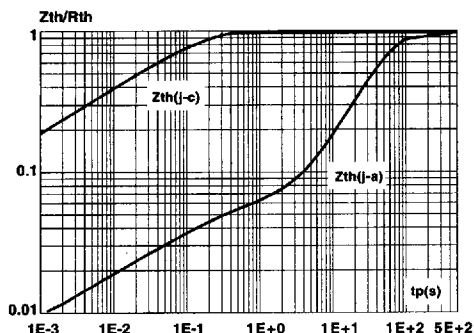


Fig.7 : Non Repetitive surge peak on-state current versus number of cycles.

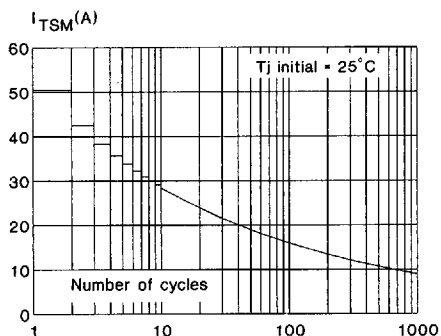


Fig.9 : On-state characteristics (maximum values).

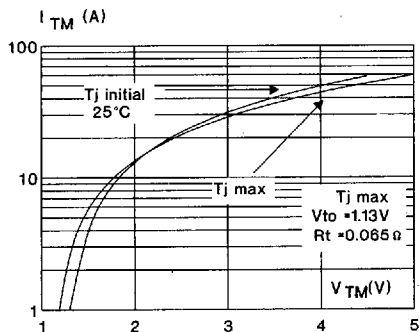


Fig.6 : Relative variation of gate trigger current and holding current versus junction temperature.

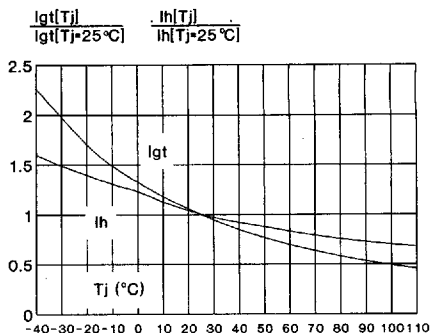
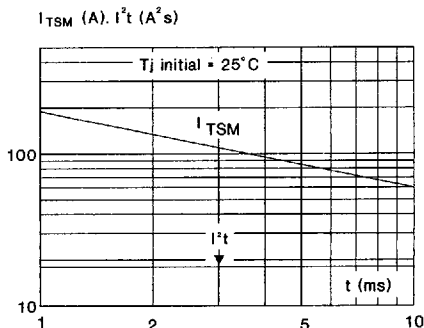
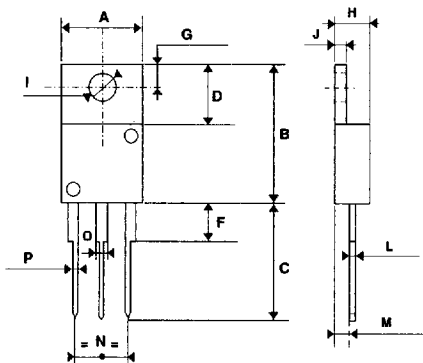


Fig.8 : Non repetitive surge peak on-state current for a sinusoidal pulse with width : $t \leq 10\text{ms}$, and corresponding value of I^2t .



PACKAGE MECHANICAL DATA

TO220AB Plastic



REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	10.20	10.50	0.401	0.413
B	14.23	15.87	0.560	0.625
C	12.70	14.70	0.500	0.579
D	5.85	6.85	0.230	0.270
F		4.50		0.178
G	2.54	3.00	0.100	0.119
H	4.48	4.82	0.176	0.190
I	3.55	4.00	0.140	0.158
J	1.15	1.39	0.045	0.055
L	0.35	0.65	0.013	0.026
M	2.10	2.70	0.082	0.107
N	4.58	5.58	0.18	0.22
O	0.80	1.20	0.031	0.048
P	0.64	0.96	0.025	0.038

Cooling method : C

Marking : type number

Weight : 2.3 g

Recommended torque value : 0.8 m.N.

Maximum torque value : 1 m.N.